



SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

LV5683P — Monolithic Linear IC

For Car Audio Systems

Multi Voltage Regulator IC

Overview

The LV5683P is a multi voltage regulator suitable for USB silicon tuner car-audio systems. This IC has 4 outputs, V_{DD} 5V(3.3V), AUDIO(8.5V), SWU(3.3V) and USB5V(CD 8V: available). About protection circuits, it has Over-current-protection, Over-voltage-protection and Thermal-shut-down. V_{CC1} (SWU and USB supply) is independent terminal from V_{CC} , and accepts lower voltage(ex. From DC/DC converter) which enables to reduce power dissipation.

Features

- 4 system regulator
 - V_{DD} (LCD micon) : V_{OUT} 5.0V(3.3V), I_O max 300mA, reverse current prevention.
 - Audio : V_{OUT} 8.5V, I_O max 300mA
 - SWU(systems) : V_{OUT} 3.3V, I_O max 500mA
 - USB : V_{OUT} 5.0V(8.0V available for CD), I_O max 1100mA
- Over-current-protection
- Over-voltage-protection: Typ 21V(except V_{DD})
- Thermal-shut-down Typ 175°C
- Applied Pch-LDMOS for output stages.

(Warning)The protector functions only improve the IC's tolerance and they do not guarantee the safety of the IC if used under the conditions out of safety range or ratings. Use of the IC such as use under overcurrent protection range or thermal shut down state may degrade the IC's reliability and eventually damage the IC.

Specifications

Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$

Parameter	Conditions	Conditions	Ratings	Unit
Supply voltage	V_{CC} max		36	V
Allowable Power dissipation	P_d max (* $T_a \leq 25^\circ\text{C}$)	IC unit	1.3	W
		With Al heatsink(50×50×1.5mm ³)	5.3	W
		Infinite heat radiation	26	W
Peak supply voltage	V_{CC} peak	See below pulse wave.	50	V
Operating ambient temperature	T_{opr}		-40 to +85	°C
Storage temperature	T_{stg}		-55 to +150	°C
Junction temperature	T_j max		150	°C

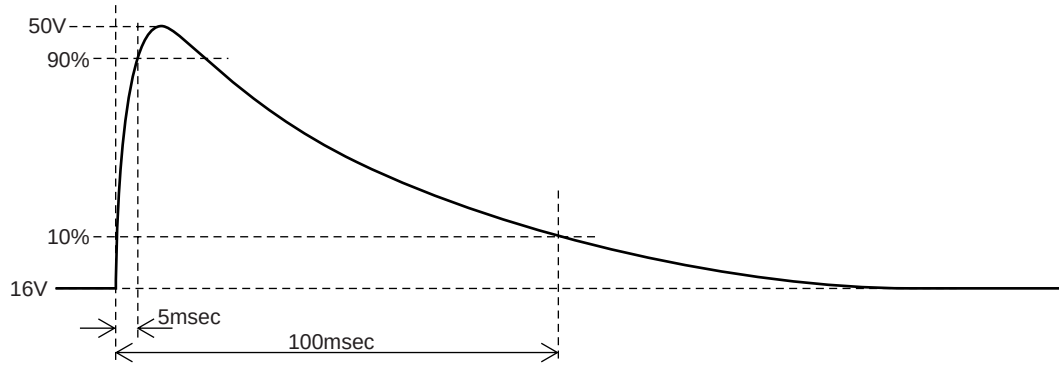
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Peak voltage testing pulse wave

Recommended Operating condition at $T_a = 25^{\circ}\text{C}$

Parameter	Conditions	Ratings	Unit
Power supply voltage rating 1	V_{DD} output(5V/3.3V)	7 to 16	V
Power supply voltage rating 2	USB(5V) output, SWU output: $V_{CC}=V_{CC1}$	7.5 to 16	V
Power supply voltage rating 3	AUDIO output	10 to 16	V
Power supply voltage rating 4	USB(8V) output: $V_{CC}=V_{CC1}$	10.5 to 16	V

Electrical Characteristics at $T_a = 25^{\circ}\text{C}$, $V_{CC} = V_{CC1} = 14.4\text{V}$ (*1)

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Quiescent current	I_{CC}	V_{DD} no load, ALL EN terminal = "L"		50	100	μA
AUDIO_EN Input						
Low input voltage	V_{IL1}		0		0.5	V
High input voltage	V_{IH1}		2.8		5.5	V
Input impedance	R_{IH1}		280	400	520	$\text{k}\Omega$
SWU_EN Input						
Low input voltage	V_{IL2}		0		0.5	V
High input voltage	V_{IH2}		2.8		5.5	V
Input impedance	R_{IH2}		280	400	520	$\text{k}\Omega$
USB_EN input						
Low input voltage	V_{IL3}		0		0.5	V
High input voltage	V_{IH3}		2.8		5.5	V
Input impedance	R_{IH3}		280	400	520	$\text{k}\Omega$
V_{DD} (5V/3.3V)output(reverse current prevention diode implemented)						
V_{DD} output voltage 1	V_{O11}	$I_{O11} = 200\text{mA}$, $IKV_{DD}=\text{OPEN}$, or $V_{DD}\text{out}$	4.75	5.0	5.25	V
V_{DD} output current 1	I_{O11}	$V_{O11} \geq 4.7\text{V}$	300			mA
V_{DD} output voltage 2	V_{O12}	$I_{O12} = 200\text{mA}$, $IKV_{DD}=\text{GND}$	3.13	3.3	3.47	V
V_{DD} output current 2	I_{O12}	$V_{O12} \geq 3.1\text{V}$	300			mA
Line regulation	ΔV_{OLN1}	$7\text{V} < V_{CC} < 16\text{V}$, $I_{O1} = 200\text{mA}$		50	100	mV
Load regulation	ΔV_{OLD1}	$1\text{mA} < I_{O11}$, $I_{O12} < 200\text{mA}$		80	150	mV
Dropout voltage 1	V_{DROP1}	$I_{O1} = 200\text{mA}$ (implemented diode)		1.5	2.5	V
V_{CC} ripple rejection	R_{REJ1}	$f=120\text{Hz}$, $V_{CC}=1\text{V}_{PP}$, $I_{O1}=200\text{mA}$	40(*2)	50(*2)		dB
V_{DD} reverse current	I_{REV}	$V_{O11}=5.0\text{V}$, $V_{CC}=0\text{V}$		10	100	μA
USB/CD output ; USB_EN = High						
USB output voltage 1	V_{O21}	$I_{O21} = 200\text{mA}$, $IK_{USB}=\text{OPEN}$, or $USB\text{out}$	7.6	8.0	8.4	V
USB output current 1	I_{O21}	$V_{O21} \geq 7.45\text{V}$	1100			mA
USB output voltage 2	V_{O22}	$I_{O22} = 1000\text{mA}$, $IK_{USB}=\text{GND}$	4.75	5.0	5.25	V
USB output current 2	I_{O22}	$V_{O22} \geq 4.6\text{V}$	1100			mA
Line regulation	ΔV_{OLN2}	$10.5\text{V} < V_{CC1} < 16\text{V}$, $I_{O2} = 1000\text{mA}$		50	100	mV
Load regulation	ΔV_{OLD2}	$10\text{mA} < I_{O21}$, $I_{O22} < 1000\text{mA}$		100	200	mV
Dropout voltage 1	V_{DROP2}	I_{O21} , $I_{O22} = 1000\text{mA}$		1.0	2.0	V
V_{CC1} ripple rejection	R_{REJ2}	$f=120\text{Hz}$, $V_{CC1}=1\text{V}_{PP}$, $I_{O2}=1000\text{mA}$	40(*2)	50(*2)		dB

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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
AUDIO output ; AUDIO_EN = High						
AUDIO output voltage	V _{O3}	I _{O3} = 200mA	8.1	8.5	8.9	V
AUDIO output current	I _{O3}	V _{O3} ≥ 8V	300			μA
Line regulation	ΔV _{OLN3}	10V < V _{CC} < 16V, I _{O3} = 200mA		30	100	mV
Load regulation	ΔV _{OLD3}	1mA < I _{O3} < 200mA		70	140	mV
Dropout voltage	V _{DROP3}	I _{O3} = 200mA		0.4	0.7	V
V _{CC} ripple rejection	R _{REJ3}	f = 120Hz, V _{CC} =1V _{PP} , I _{O3} =200mA	40(*2)	50(*2)		dB
SWU (3.3V) Output ; SEU_EN = High						
ILM output voltage	V _{O4}	I _{O4} = 400mA	3.13	3.3	3.47	V
ILM output current	I _{O4}	V _{O4} ≥ 3.1V	500			mA
Line regulation	ΔV _{OLN4}	7.5V < V _{CC1} < 16V, I _{O4} = 400mA		30	100	mV
Load regulation	ΔV _{OLD4}	1mA < I _{O4} < 400mA		80	150	mV
V _{CC1} ripple rejection	R _{REJ4}	f = 120Hz, V _{CC1} =1V _{PP} , I _{O4} =400mA	40(*2)	50(*2)		dB

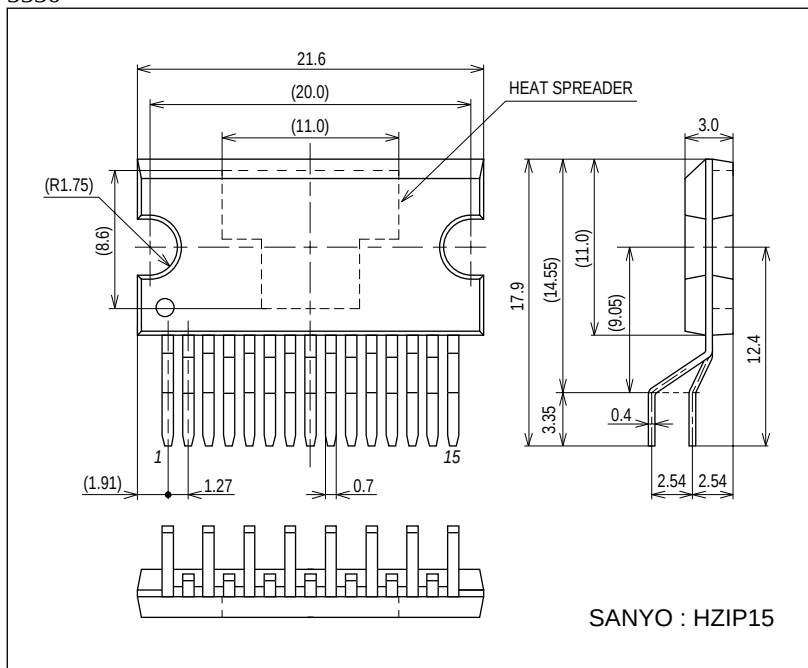
*1: The entire specification has been defined based on the tests performed under the conditions where T_j and $T_a(=25^\circ\text{C})$ are almost equal. There tests were performed with pulse load to minimize the increase of junction temperature(T_j).

*2 : design certification

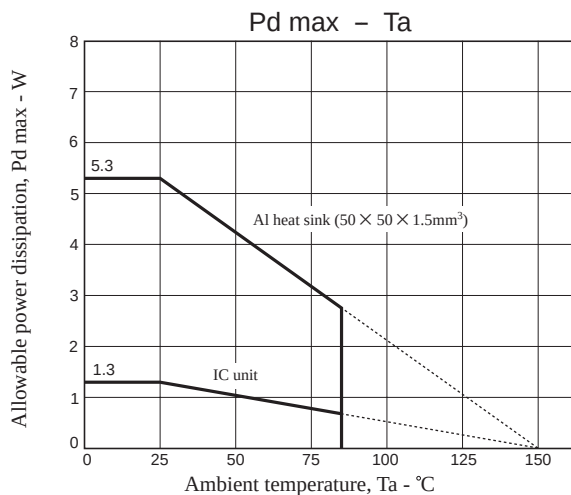
Package Dimensions

unit : mm (typ)

3336

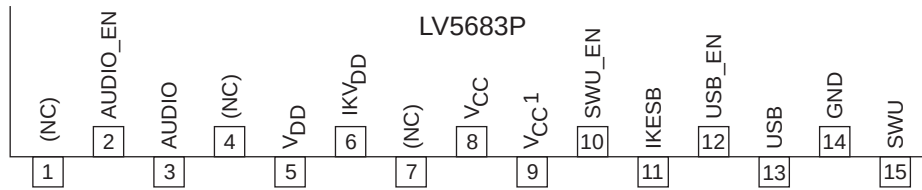


Allowable power dissipation derating curve

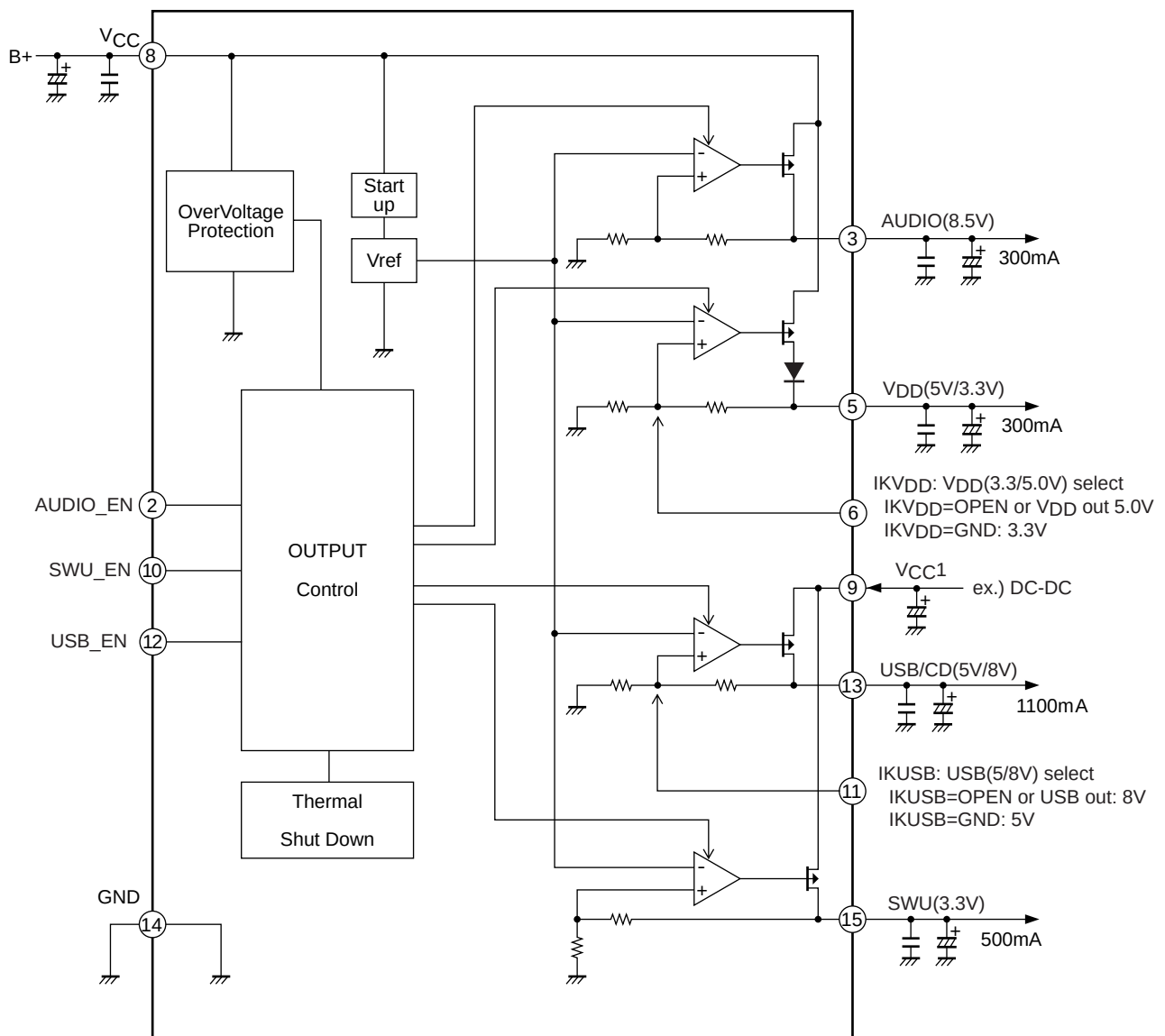


- (a) IC unit(HZIP15)
- (b) With Al heatsink($50 \times 50 \times 1.5\text{mm}^3$)
Al heatsink mounting conditions
Tightening torque: 39N·cm, using silicone grease

Pin assignment



Block Diagram



Pin Function

Pin No.	Pin name	Description	Equivalent Circuit
1	N.C.	-	-
2	AUDIO_EN	AUDIO output CTRL	
3	AUDIO	AUDIO output when AUDIO_EN = High, ON 8.5V/0.3A	
4	N.C.	-	-
5	V _{DD}	V _{DD} output 5.0V, 3.3V/0.3A	
6	IKV _{DD}	V _{DD} output voltage select OPEN : V _{DD} = 5.0V GND : V _{DD} = 3.3V	
7	N.C.	-	-
8	V _{CC}	V _{CC}	
9	V _{CC1}	V _{CC1}	

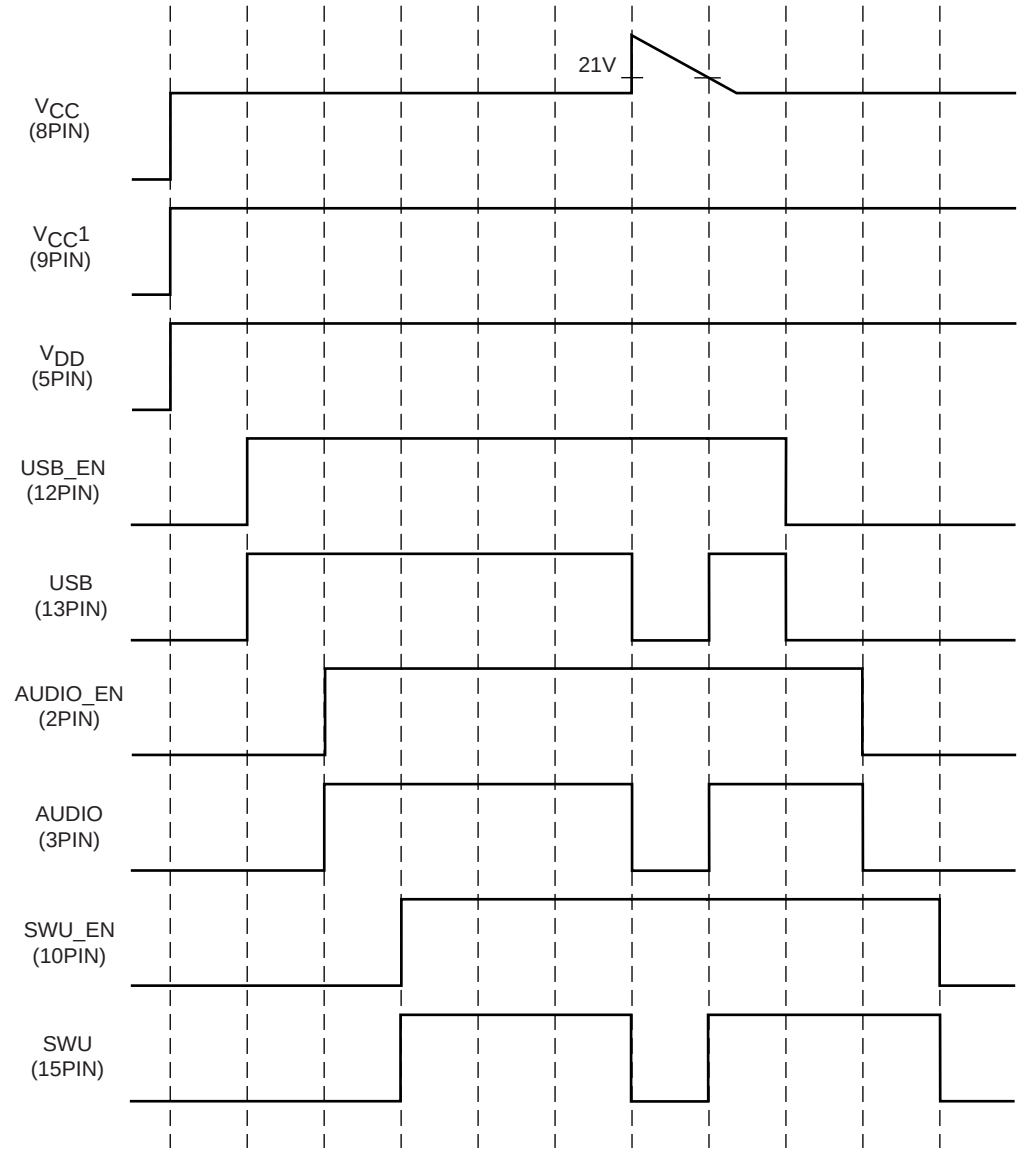
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Pin No.	Pin name	Description	Equivalent Circuit
10	SWU_EN	SWU output CTRL	
11	IKUSB	USB output voltage select OPEN : $V_{DD} = 8.0V$ GND : $V_{DD} = 5.0V$	
12	USB_EN	USB output CTRL	
13	USB	USB output when USB_EN = High, ON 5.0V, 8.0V/1.1A	
14	GND	GND	
15	SWU	SWU output when SWU_EN = High, ON 3.3V/0.5A	

Timing Chart



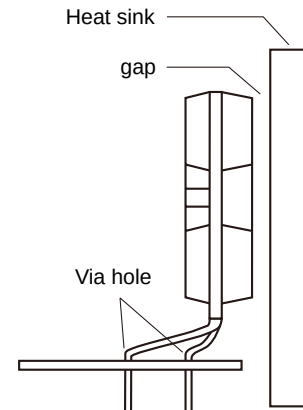
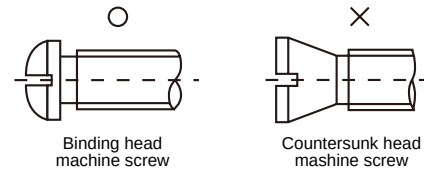
HZIP15 Heat sink attachment

Heat sinks are used to lower the semiconductor device junction temperature by leading the heat generated by the device to the outer environment and dissipating that heat.

- a. Unless otherwise specified, for power ICs with tabs and power ICs with attached heat sinks, solder must not be applied to the heat sink or tabs.

- b. Heat sink attachment

- Use flat-head screws to attach heat sinks.
- Use also washer to protect the package.
- Use tightening torques in the ranges 39-59Ncm(4-6kgcm) .
- If tapping screws are used, do not use screws with a diameter larger than the holes in the semiconductor device itself.
- Do not make gap, dust, or other contaminants to get between the semiconductor device and the tab or heat sink.
- Take care a position of via hole .
- Do not allow dirt, dust, or other contaminants to get between the semiconductor device and the tab or heat sink.
- Verify that there are no press burrs or screw-hole burrs on the heat sink.
- Warping in heat sinks and printed circuit boards must be no more than 0.05 mm between screw holes, for either concave or convex warping.
- Twisting must be limited to under 0.05 mm.
- Heat sink and semiconductor device are mounted in parallel.
- Take care of electric or compressed air drivers
- The speed of these torque wrenches should never exceed 700 rpm, and should typically be about 400 rpm.



- c. Silicone grease

- Spread the silicone grease evenly when mounting heat sinks.
- Sanyo recommends YG-6260 (Momentive Performance Materials Japan LLC)

- d. Mount

- First mount the heat sink on the semiconductor device, and then mount that assembly on the printed circuit board.
- When attaching a heat sink after mounting a semiconductor device into the printed circuit board, when tightening up a heat sink with the screw, the mechanical stress which is impossible to the semiconductor device and the pin doesn't hang.

- e. When mounting the semiconductor device to the heat sink using jigs, etc.,

- Take care not to allow the device to ride onto the jig or positioning dowel.
- Design the jig so that no unreasonable mechanical stress is not applied to the semiconductor device.

- f. Heat sink screw holes

- Be sure that chamfering and shear drop of heat sinks must not be larger than the diameter of screw head used.
- When using nuts, do not make the heat sink hole diameters larger than the diameter of the head of the screws used. A hole diameter about 15% larger than the diameter of the screw is desirable.
- When tap screws are used, be sure that the diameter of the holes in the heat sink are not too small. A diameter about 15% smaller than the diameter of the screw is desirable.

- g. There is a method to mount the semiconductor device to the heat sink by using a spring band. But this method is not recommended because of possible displacement due to fluctuation of the spring force with time or vibration.

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